

# InGaAs 2 – 3 mm Quadrant PIN Preamplifier Module



CMC Electronics' 264-339838 series is a combination of InGaAs quadrant PIN receivers with four (4) built-in trans-impedance amplifiers in a 1-inch 12-lead TO-can package.

Customizations to bandwidth, rise time and responsivity will be available upon request.

## Features

- 2 – 3 mm diameter quadrant InGaAs PIN
- 40 MHz bandwidth
- Low noise Equivalent Power (NEP)
- Spectral Response: 1000 – 1600 nm
- Eye safe operating band
- Common Cathode configuration
- Hermetically Sealed 1-inch TO-can

## Applications

- Free-Space Optical (FSO) Communication
- Precision Guided Munition (PGM)
- Laser Warning Systems (LWS)
- Laser Range Finding (LRF)
- Laser Spot Tracking
- Laser Alignment
- Position Sensor

**Table 1. Electro-Optical Common Characteristics**Conditions:  $T_{case} = 25\text{ }^{\circ}\text{C}$ ,  $V+ = 5.0\text{ V}$ ,  $V- = -5.0\text{ V}$ ,  $V\_PIN = 3.0$ ,  $\lambda = 1570\text{ nm} \pm 10\text{ nm}$ 

Parameter	Symbol	Min.	Typ.	Max.	Units
Output impedance	$R_{out}$		50		$\Omega$
Bandwidth, $f_{-3dB}$	BW		40		MHz
Rise time (10-90 %) & Fall time (90-10 %)	$t_{rise}$		10		ns
Linear Output Voltage Swing (Pulse)			1.0		V
Output Offset Voltage	$V_{oo}$	-0.1	0.0	0.1	V
Supply current V+	$I_{pos}$		35		mA
Supply current V-	$I_{neg}$		-65		mA
Channel-to-channel crosstalk			5		%
Channel uniformity				5	%

**Table 2. Electro-Optical Characteristics for 2 mm quadrant diameter**Conditions:  $T_{case} = 25\text{ }^{\circ}\text{C}$ ,  $V+ = 5.0\text{ V}$ ,  $V- = -5.0\text{ V}$ ,  $V\_PIN = 3.0$ ,  $\lambda = 1570\text{ nm} \pm 10\text{ nm}$ 

Parameter	Symbol	Min.	Typ.	Max.	Units
Responsivity					
1060 nm	R		6.0		kV/W
1550 nm			9.0		kV/W
Noise equivalent power (DC - 40 MHz) (Note 1)					
Dark conditions	NEP		12		$\text{pW}/\sqrt{\text{Hz}}$
1-sun background illumination			20		

**Note:** 1. Integration of the noise calculation is based on  $f_{-3dB}$  bandwidth.**Table 3. Electro-Optical Characteristics for 3 mm quadrant diameter**Conditions:  $T_{case} = 25\text{ }^{\circ}\text{C}$ ,  $V+ = 5.0\text{ V}$ ,  $V- = -5.0\text{ V}$ ,  $V\_PIN = 3.0$ ,  $\lambda = 1570\text{ nm} \pm 10\text{ nm}$ 

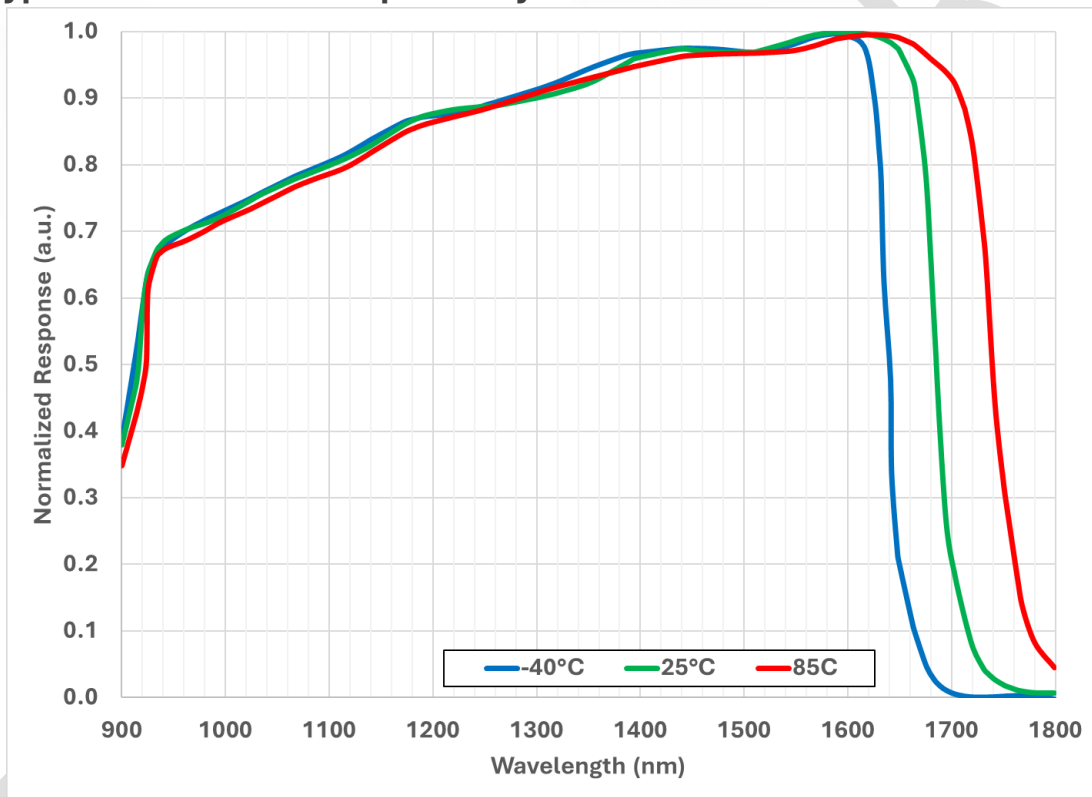
Parameter	Symbol	Min.	Typ.	Max.	Units
Responsivity					
1060 nm	R		4.5		kV/W
1550 nm			6.5		kV/W
Noise equivalent power (DC - 40 MHz) (Note 1)					
Dark conditions	NEP		20		$\text{pW}/\sqrt{\text{Hz}}$
1-sun background illumination			30		

**Note:** 1. Integration of the noise calculation is based on  $f_{-3dB}$  bandwidth.

**Table 3. Absolute-Maximum Ratings, Limiting Values**

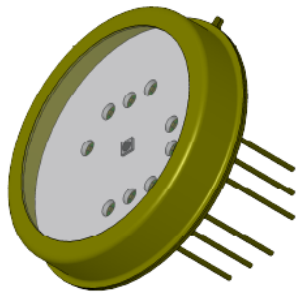
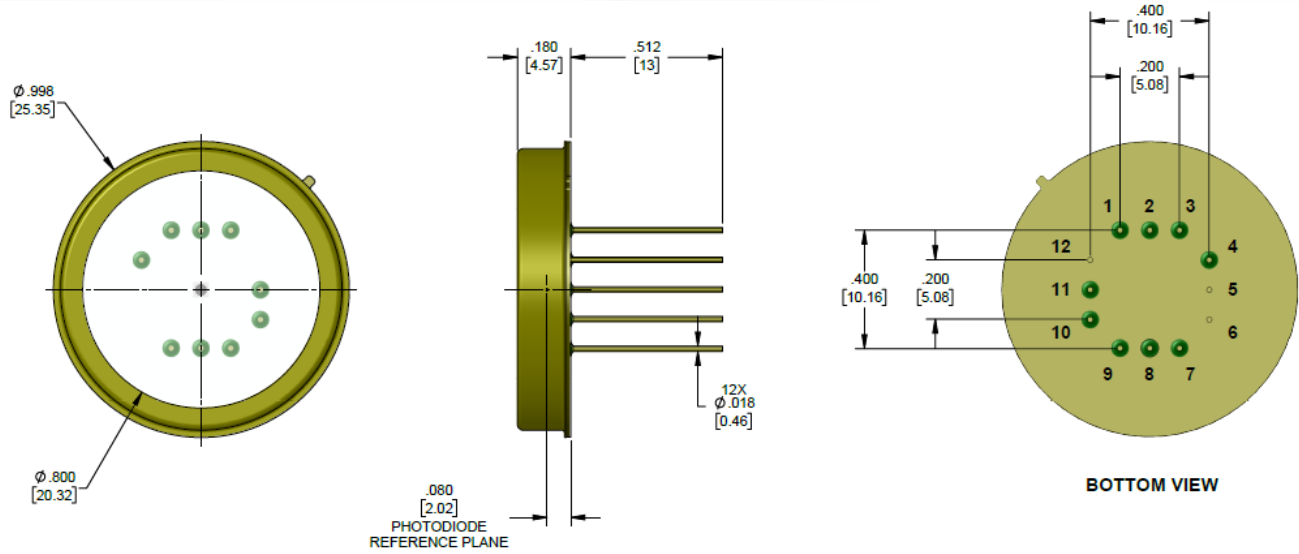
Parameter	Symbol	Min.	Max.	Units
Average photocurrent	$I_{ave}$		5	mA
Pre-amplifier Voltage V+	$V_{pos}$		6.5	V
Pre-amplifier Voltage V-	$V_{neg}$	-6.5		V
Quadrant PIN Breakdown Voltage	$V_{br}$		12	V
Operating Temperature	$T_{op}$	-40	85	°C
Storage Temperature	$T_{stor}$	-55	125	°C
Soldering Temperature (5 s, leads only)			250	°C

**Figure 1. Typical Normalized Responsivity**



### Figure 2. Package Dimension and Pinout

Unless otherwise specified, dimensions are in inches (mm) and are for reference only.



PINOUT			
1	OUT1	7	OUT3
2	V+	8	V-
3	OUT2	9	OUT4
4	N/C	10	V_PIN
5	GND	11	N/C
6	GND	12	GND

DIMENSIONS ARE IN INCHES [ MILLIMETERS ]  
AND ARE FOR REFERENCE ONLY

### Table 4. Ordering Guide

VAR	Typical Bandwidth	Active Diameter	Comments
264-339838-001	40 MHz	3 mm	
264-339838-002	40 MHz	2 mm	



For more information, visit [www.cmcelectronics.ca/optoelectronics](http://www.cmcelectronics.ca/optoelectronics)  
or email us at [opto@cmcelectronics.ca](mailto:opto@cmcelectronics.ca)

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